P-Channel 30-V (D-S) MOSFET

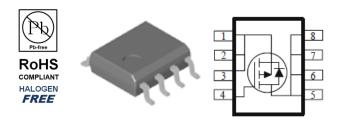
Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- Fast switching speed

Typical Applications:

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY			
Vds (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
-30	5 @ VGS = -10V	-21	
-30	7 @ VGS = -4.5V	-17	



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage		V _{DS}	-30	V	
Gate-Source Voltage	V _{GS}	±20	V		
Continuous Drain Current ^a	T _A =25°C		-21		
Continuous Drain Current	T _A =70°C	I _D	-17	А	
Pulsed Drain Current ^b	I _{DM}	-80			
Continuous Source Current (Diode Conduction) ^a		I _S	-4.8	А	
Dower Dissinction ^a	T _A =25°C	P _D	3.1	W	
Power Dissipation ^a	T _A =70°C	'D	2.2	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
Maximum Junction-to-Ambient ^a	t <= 10 sec	R _{eja}	40	°C/W	
	Steady State	INθJA	80		

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

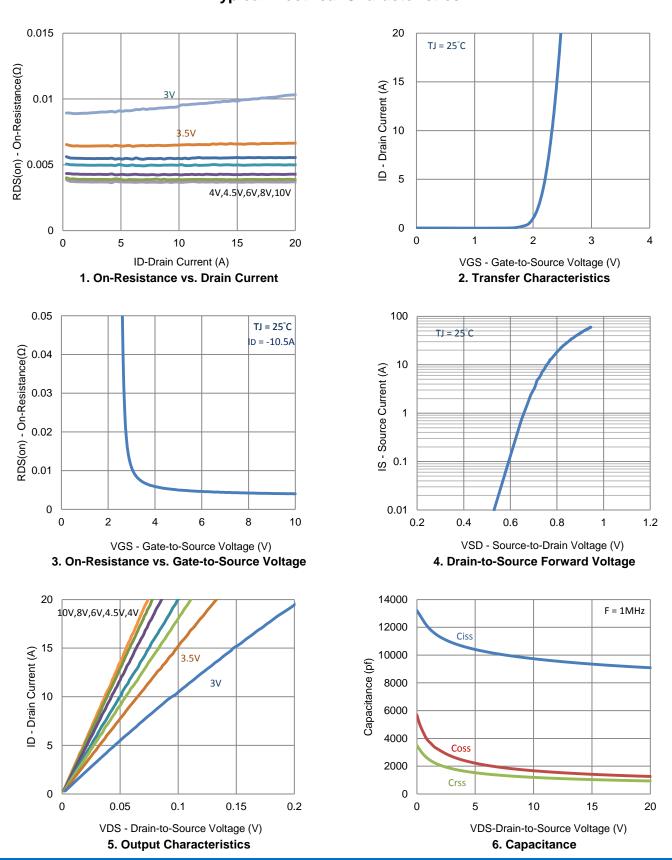
Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	1			V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current	1	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$	-1		-1	uA
Zero Gale Voltage Drain Current	IDSS	V _{DS} = -24 V, V _{GS} = 0 V, T _J = 55°C			-25	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -10 V$	-30			Α
Drain Sauras On Desistance a	r	V_{GS} = -10 V, I_{D} = -10.5 A			5	
Drain-Source On-Resistance ^a	r _{DS(on)}	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -8.5 \text{ A}$			7	mΩ
Forward Transconductance ^a	g _{fs}	$V_{DS} = -15 \text{ V}, \text{ I}_{D} = -10.5 \text{ A}$		32		S
Diode Forward Voltage ^a	V_{SD}	$I_{S} = -2.4 \text{ A}, V_{GS} = 0 \text{ V}$		-0.68		V
Dynamic ^b						
Total Gate Charge	Qg	V _{DS} = -15 V, V _{GS} = -4.5 V,		136		
Gate-Source Charge	Q_gs	$V_{DS} = -13 V, V_{GS} = -4.3 V,$ $I_{D} = -10.5 A$		31		nC
Gate-Drain Charge	Q_gd	1 <u>0</u> - 10.0 K		59		
Turn-On Delay Time	t _{d(on)}	$V_{DS} = -15 \text{ V}, \text{ R}_{L} = 1.9 \Omega,$		19		
Rise Time	t _r	$V_{DS} = -15 V, R_L = 1.9 \Omega,$ $I_D = -10.5 A,$		64		20
Turn-Off Delay Time	t _{d(off)}	$V_{GEN} = -10 \text{ V}, R_{GEN} = 6 \Omega$		365		ns
Fall Time	t _f	$V_{\text{GEN}} = 10$ V, $V_{\text{GEN}} = 0.22$		224		
Input Capacitance	C _{iss}			9350		
Output Capacitance	C _{oss}	V_{DS} = -15 V, V_{GS} = 0 V, f = 1 MHz		1415		рF
Reverse Transfer Capacitance	C _{rss}			1034		

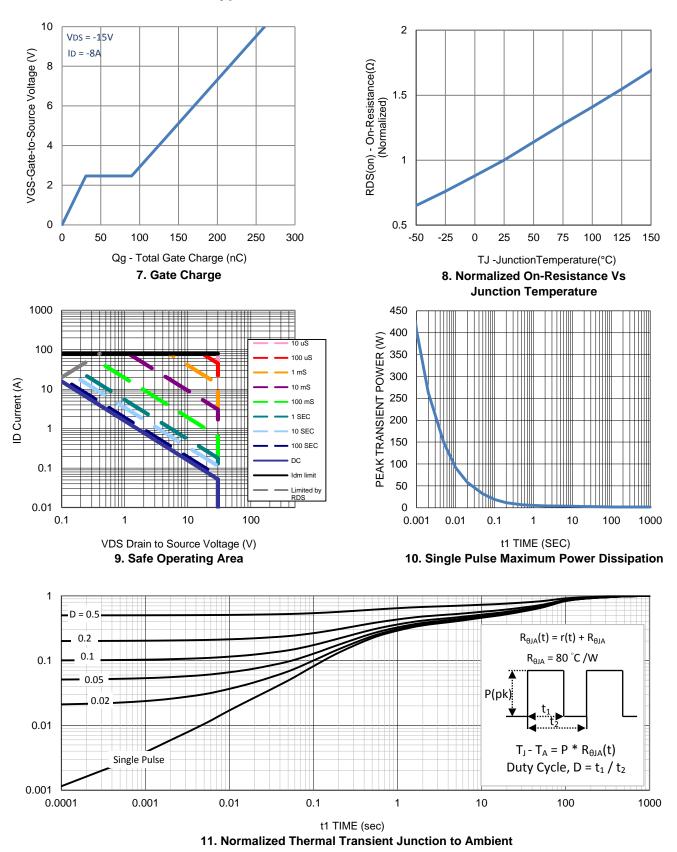
Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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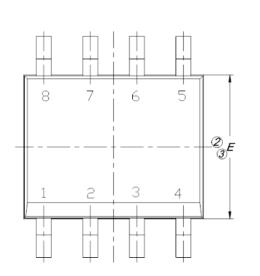
Typical Electrical Characteristics

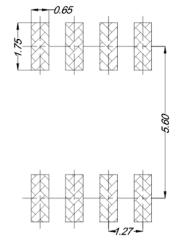


Typical Electrical Characteristics

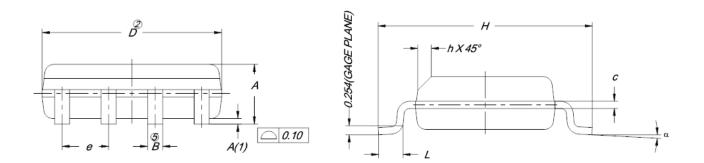
Package Information

Land Pattern (Only for Reference)





514	MILLIMETERS				
DIM.	MIN.	NOM.	MAX.		
А	1.35	1.55	1.75		
A(1)	0.10	0.18	0.25		
В	0.38	0.45	0.51		
С	0.19	0.22	0.25		
D	4.80	4.90	5.00		
E	3.80	3.90	4.00		
е	1.27 BSC				
н	5.80	6.00	6.20		
L	0.50	0.72	0.93		
α	0°	4°	8°		
h	0.25	0.38	0.50		



Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
- 4. The Package Top May Be Smaller Than The Package Bottom.
- Dimension "B" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.08 mm Total In Excess Of "B" Dimension At Maximum Material Condition. The Dambar Cannot Be Located On The Lower Radius Of The Foot.